

SPECIFICATION

Device Name : IGBT Module

Type Name : 7MBR30SA060E-01

Spec. No. : MS6M 0543

Date : Jun. - 02 - 2000

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Fuji Electric Co., Ltd.
Matsumoto Factory

DATE		NAME	APPROVED	Fuji Electric Co.,Ltd.	
DRAWN	Jan. - 2 - '00	T. Kobayashi	T. Hiyasaka	DWG. NO.	MS6M 0543
CHECKED	June - 2 - '00	S. Nagaoka			
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Revised Records

Date	Classi- fication	Ind.	Content	Applied date	Drawn	Checked	Approved
Jan-2-'00	enactment	—	—	Issued date	—	S. M. Hsu	T. Miyazaki

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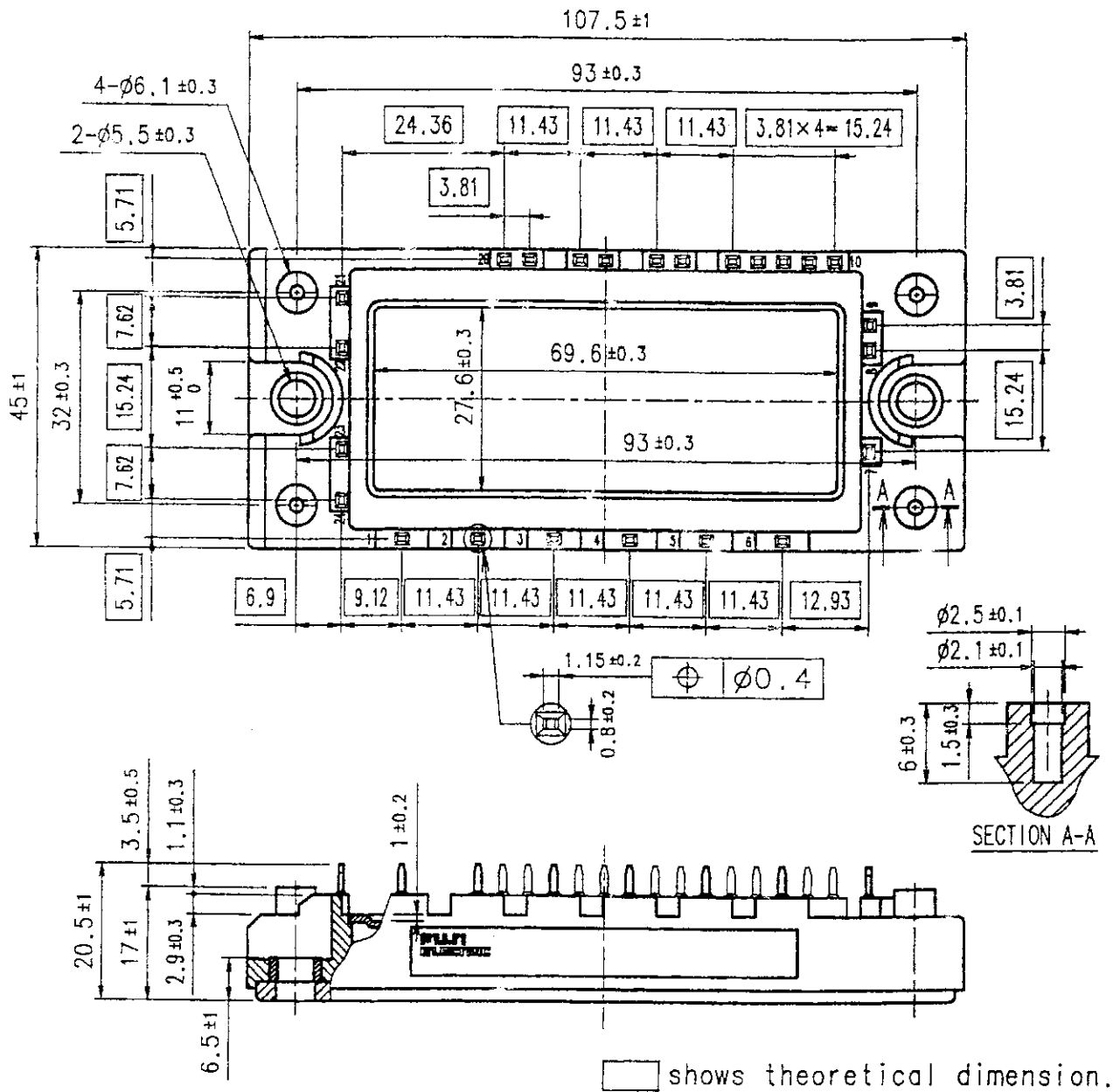
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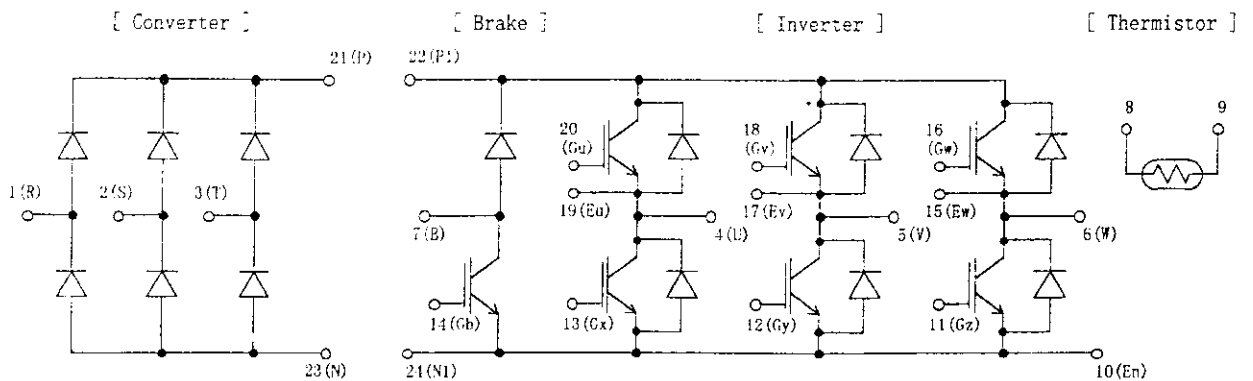
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1. Outline Drawing (Unit : mm)



2. Equivalent circuit



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3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions	Maximum Ratings	Units
Inverter	Collector-Emitter voltage	VCES		600	V
	Gate-Emitter voltage	VGES		+ -20	V
	Collector current	Ic	Continuous	30	A
		Icp	1ms	60	A
		-Ic		30	A
	Collector Power Dissipation	Pc	1 device	120	W
Brake	Collector-Emitter voltage	VCES		600	V
	Gate-Emitter voltage	VGES		+ -20	V
	Collector current	Ic	Continuous	20	A
		Icp	1ms	40	A
	Collector Power Dissipation	Pc	1 device	80	W
	Repetitive peak reverse Voltage(Diode)	VRRM		600	V
Converter	Repetitive peak reverse Voltage	VRRM		800	V
	Average Output Current	Io	50Hz/60Hz sine wave	50	A
	Surge Current (Non-Repetitive)	IFSM	Tj=150C,10ms	350	A
	I ² t (Non-Repetitive)	I ² t	half sine wave	613	A ² s
Junction temperature		Tj		150	C
Storage temperature		Tstg		-40~ +125	C
Isolation voltage	between terminal and copper base ^(*)1)	Viso	AC : 1min.	2500	V
	between thermistor and others ^(*)2)			2500	V
Mounting Screw Torque ^(*)3)				3.5	Nm

(*)1) All terminals should be connected together when isolation test will be done.

(*)2) Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*)3) Recommendable Value : 2.5~3.5 Nm (M5)

4. Electrical characteristics (at Tj= 25C unless otherwise specified)

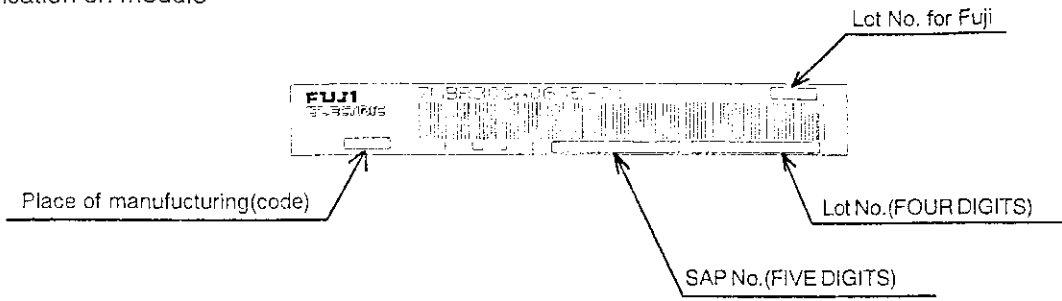
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Inverter	Zero gate voltage Collector current	ICES VGE 0 V, VCE 600 V			1.0	mA
	Gate-Emitter leakage current	IGES VCE 0 V, VGE +-20 V			200	nA
	Gate-Emitter threshold voltage	VGE(th) VCE 20 V, Ic = 30 mA	5.5	7.8	8.5	V
	Collector-Emitter saturation voltage	VCE(sat) VGE 15 V, chip		1.8		V
		Ic = 30 A terminal		1.95	2.4	
	Input capacitance	Cies VGE 0 V, VCE 10 V f = 1 MHz		3000		pF
	Turn-on time	ton Vcc= 300 V		0.45	1.2	us
		tr Ic = 30 A		0.25	0.6	
		tr(off) VGE +-15 V		0.08		
	Turn-off time	toff RG = 82 ohm		0.40	1.0	
		tf		0.05	0.35	
Brake	Forward on voltage	VF IF = 30 A chip		1.8		V
		terminal		1.95	2.6	
	Reverse recovery time	trr IF = 30 A			300	ns
	Zero gate voltage Collector current	ICES VGE 0 V, VCE 600 V			1.0	nA
	Gate-Emitter leakage current	IGES VCE 0 V, VGE +-20 V			200	nA
	Collector-Emitter saturation voltage	VCE(sat) VGE 15 V, chip		1.8		V
		Ic = 20 A terminal		1.95	2.4	
	Turn-on time	ton Vcc= 300 V		0.45	1.2	us
		tr Ic = 20 A		0.25	0.6	
	Turn-off time	toff VGE +-15 V		0.40	1.0	
		tf RG = 120 ohm		0.05	0.35	
Converter	Reverse current	IRRM VR = 600 V			1.0	mA
	Forward on voltage	VFM IF = 30 A chip		1.0		V
Thermistor	Resistance	R T = 25C		5000		ohm
		T = 100C	465	495	520	
	B value	B T = 25/50C	3305	3375	3450	K

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			1.04	C/W
		Inverter FWD			2.00	
		Brake IGBT			1.56	
		Converter Diode			0.90	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (*)		0.05		C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Indication on module



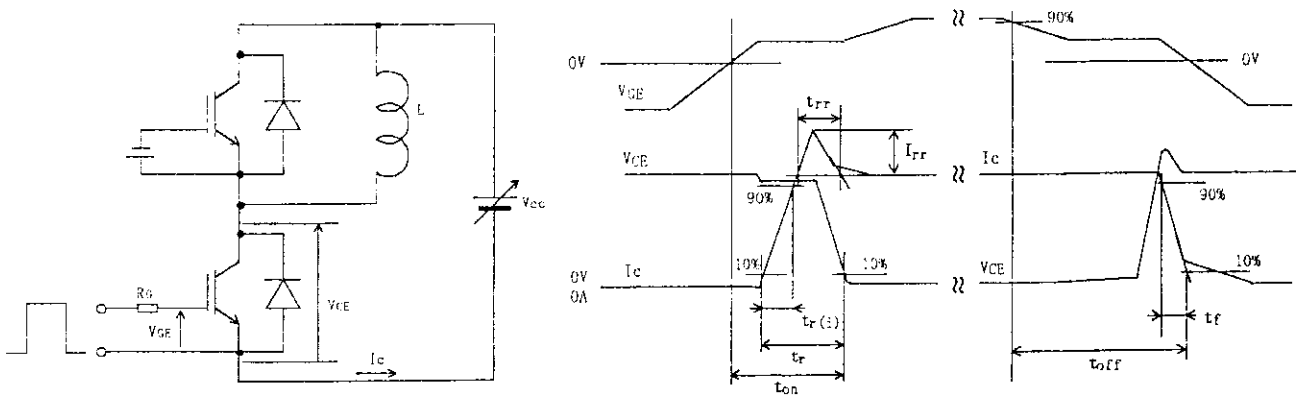
7. Applicable category

This specification is applied to Power Integrated Module named 7MBR30SA060E-01.

8. Storage and transportation notes

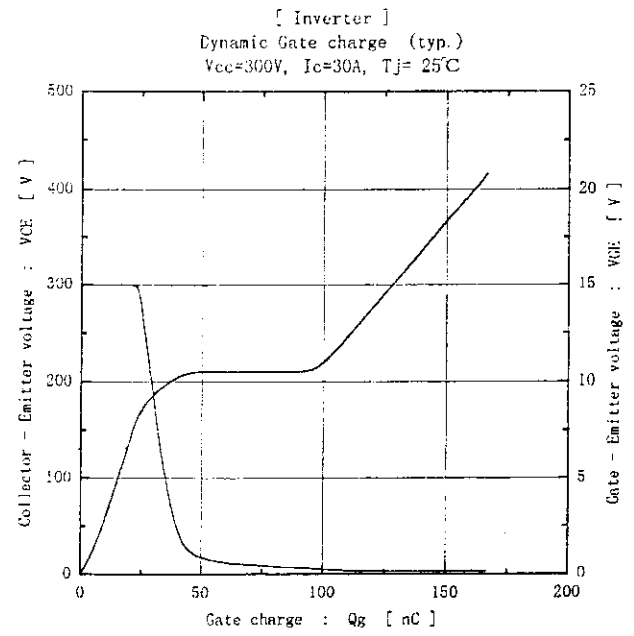
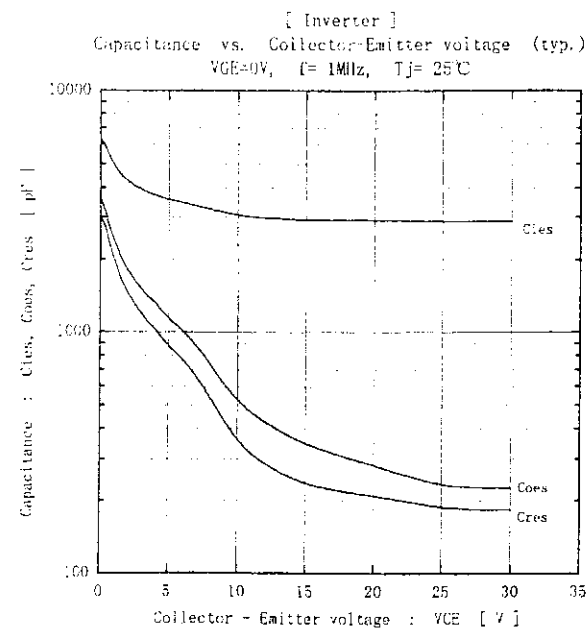
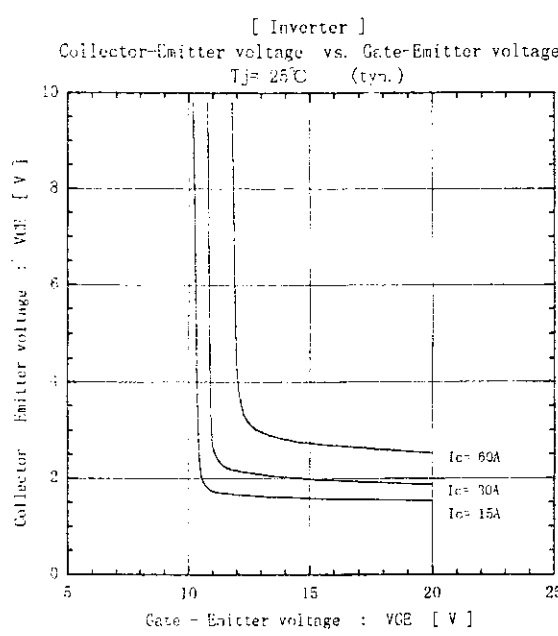
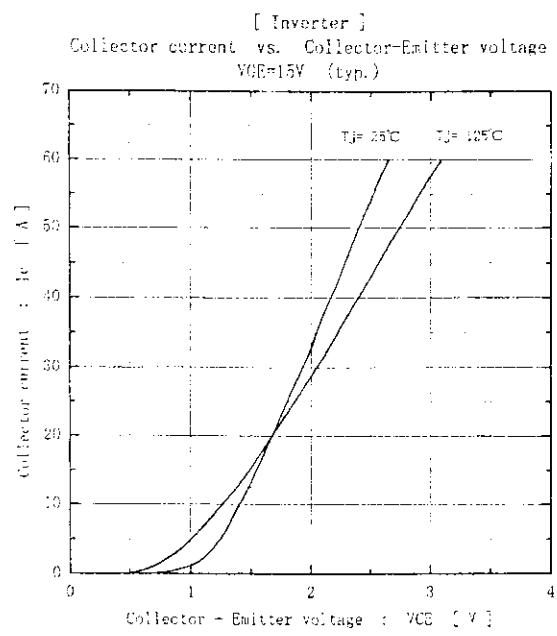
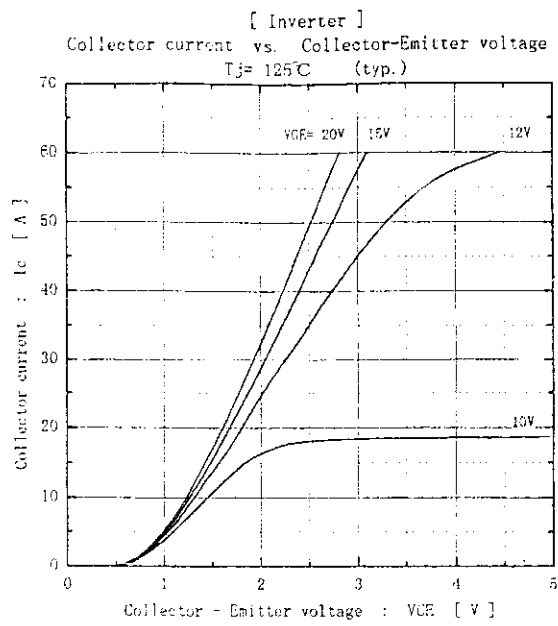
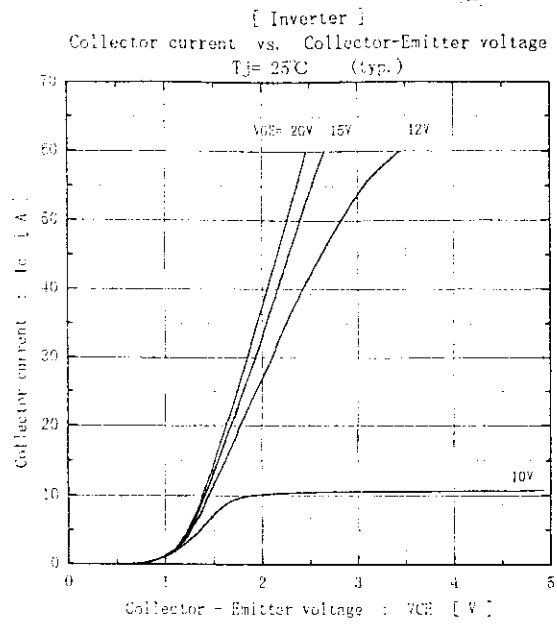
- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

9. Definitions of switching time



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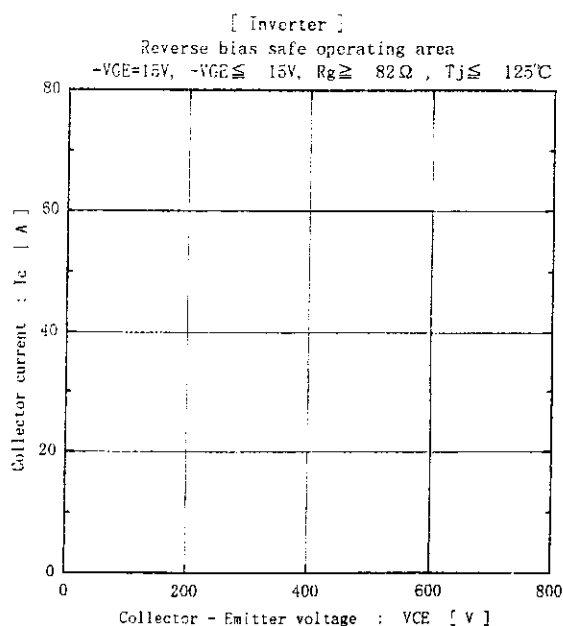
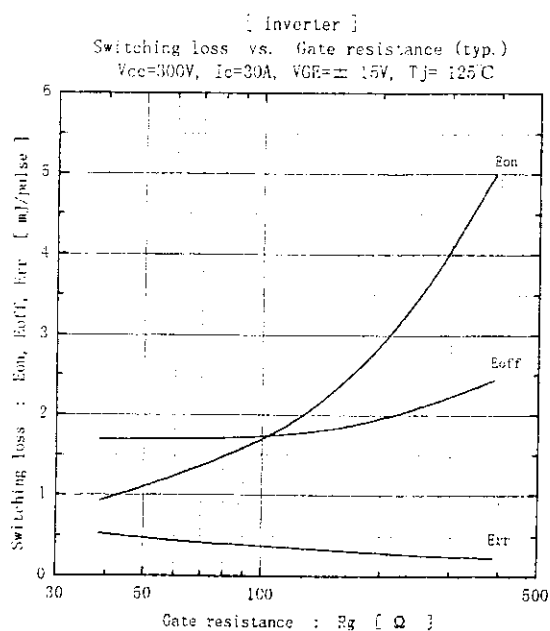
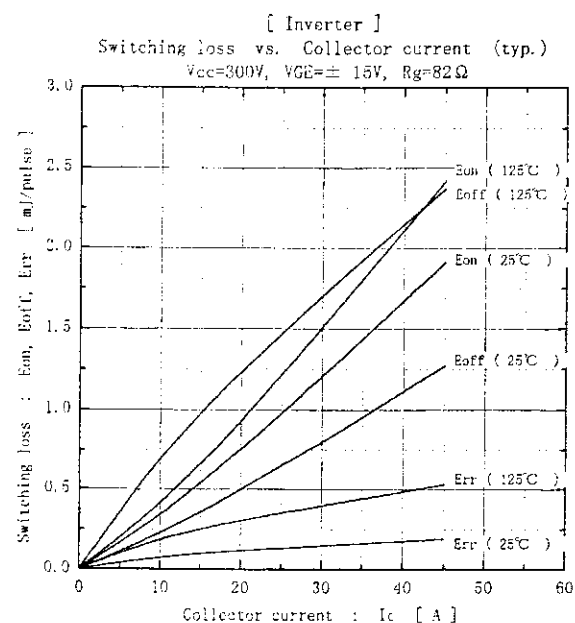
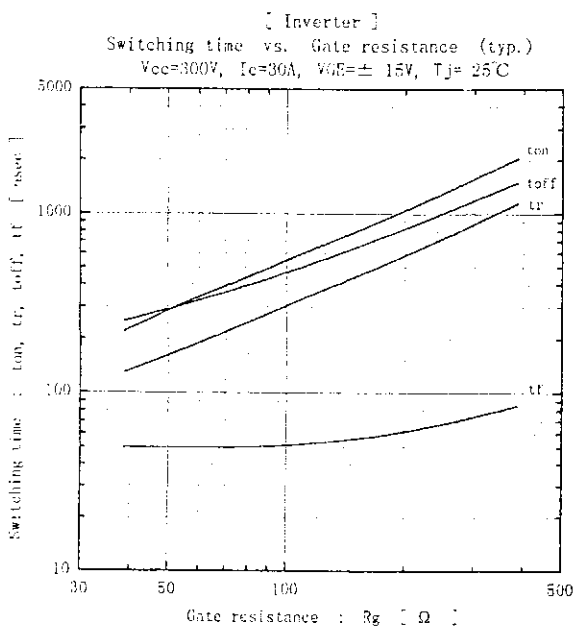
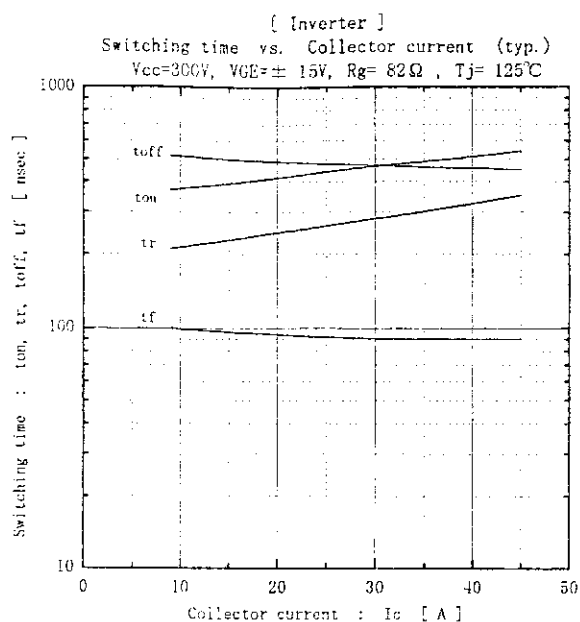
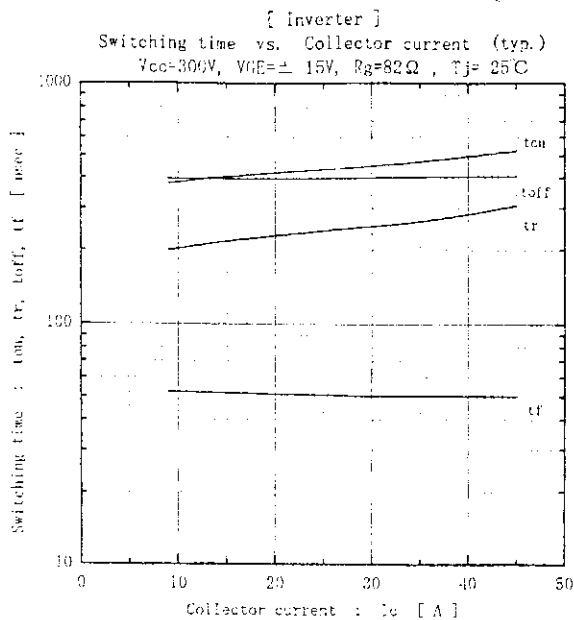
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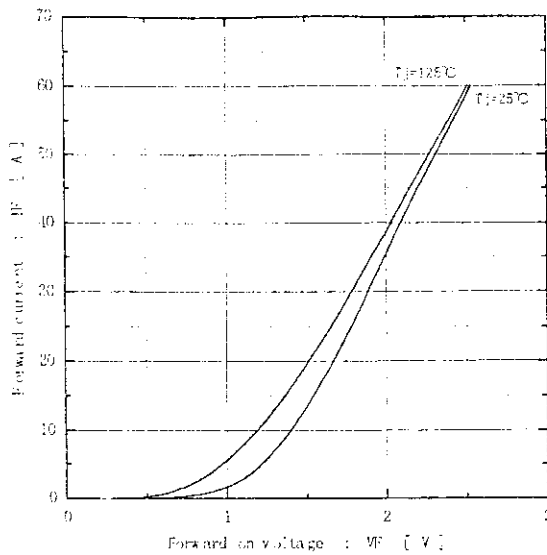
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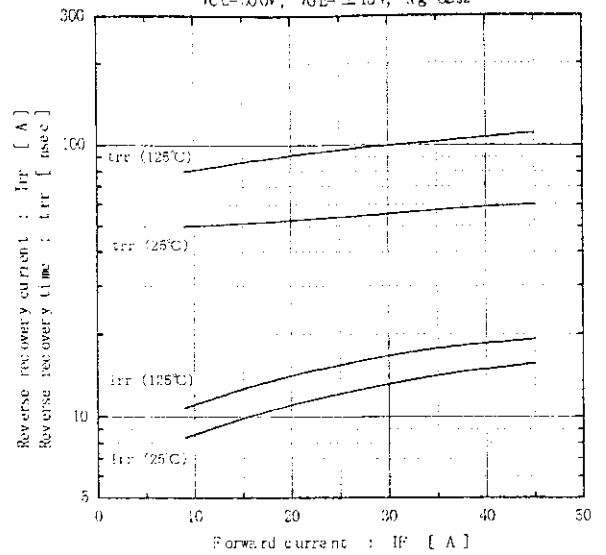


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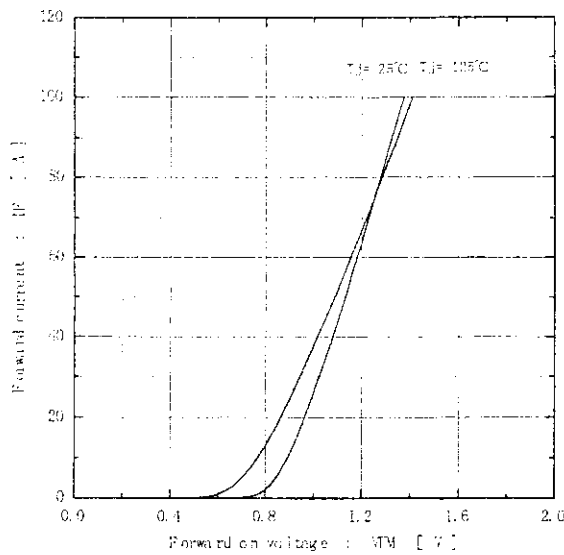
[Inverter]
Forward current vs. Forward on voltage (typ.)



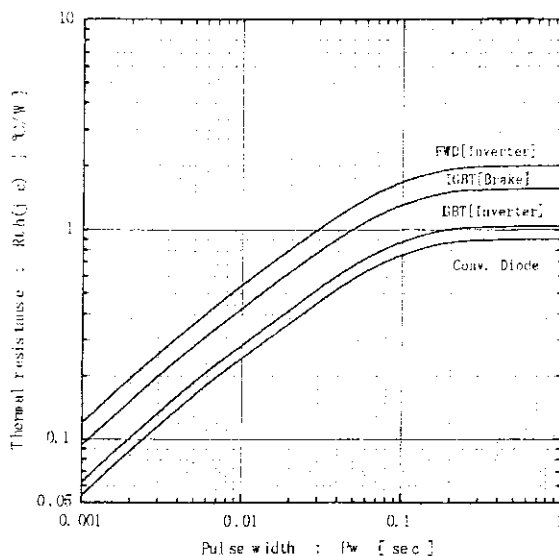
[Inverter]
Reverse recovery characteristics (typ.)
Vce=100V, VGE=±15V, Rg=82Ω



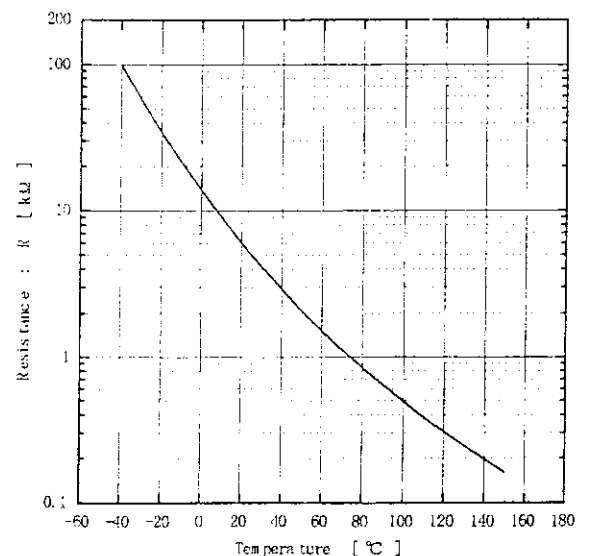
[Converter]
Forward current vs. Forward on voltage (typ.)



Transient thermal resistance



[Thermistor]
Temperature characteristic (typ.)



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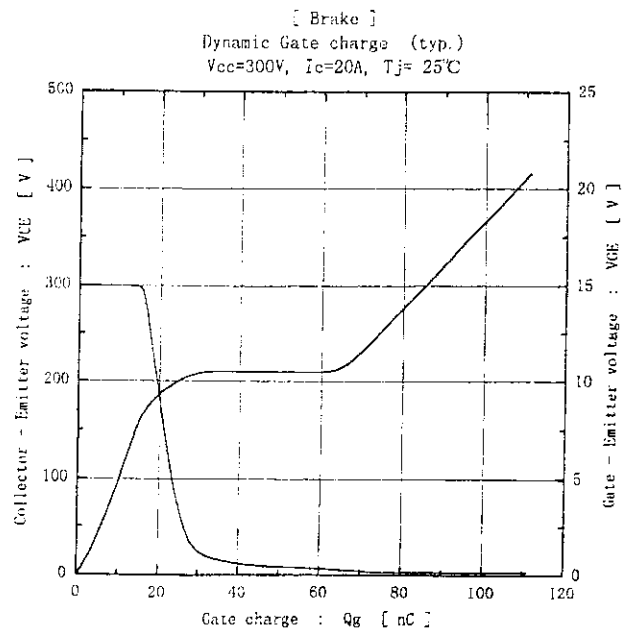
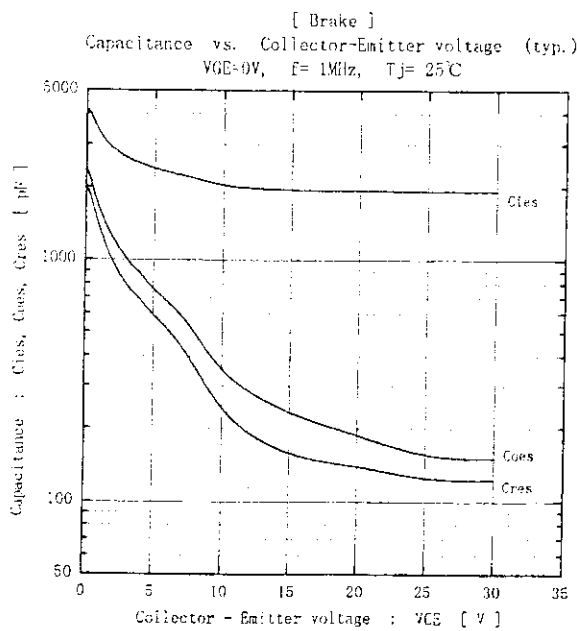
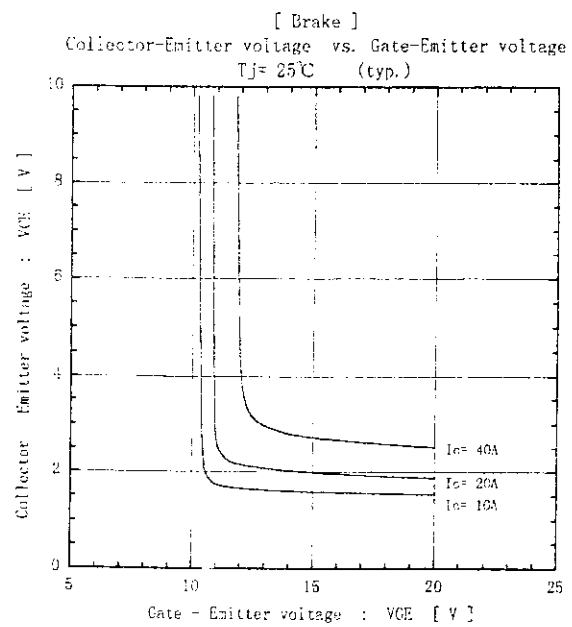
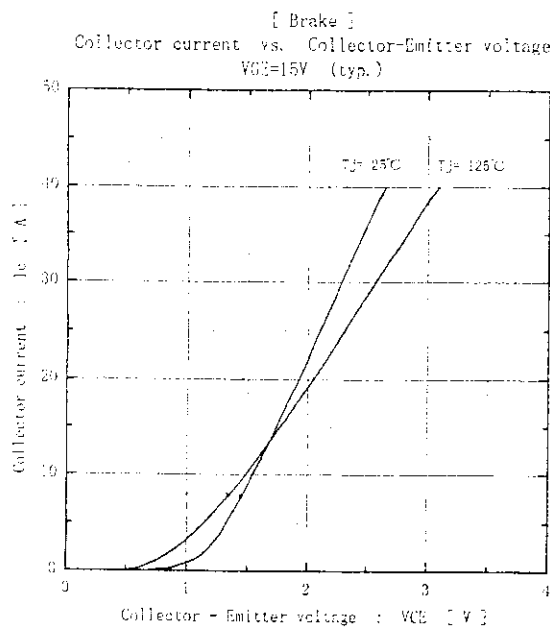
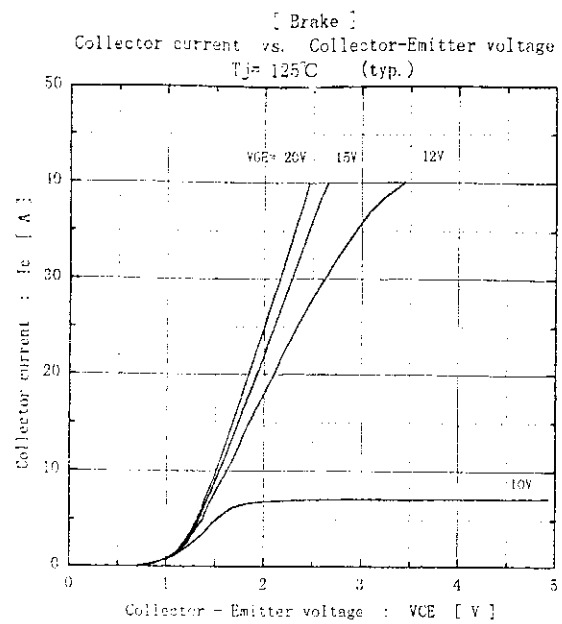
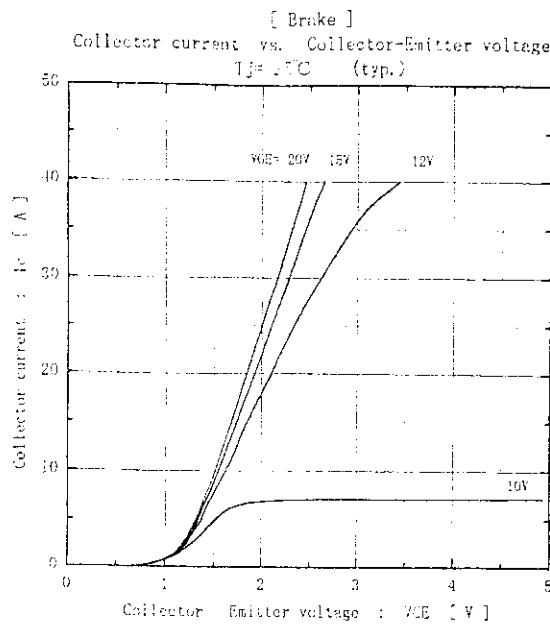
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